



60V PNP MEDIUM POWER TRANSISTOR IN SOT89

Description

Packaged in SOT89 outline, this low-saturation PNP transistor offers extremely low on-state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads,
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.05 grams (Approximate)

Features

- BV_{CEO} > -60V
- BV_{ECO} > -7V
- I_C = -4.5 High Continuous Collector Current
- I_{CM} = -7A Peak Collector Current
- V_{CE(sat)} < -80mV @ -1A
- R_{CE(sat)} = 50mΩ for a Low Equivalent On-Resistance
- P_D=2.4W
- Complementary Part Number ZXTN19060CZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

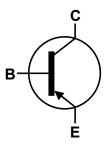
https://www.diodes.com/quality/product-definitions/

Applications

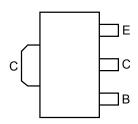
- High Side Driver
- Motor Drive
- Load Disconnect Switch







Device Symbol



Top View Pin Out

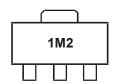
Ordering Information (Notes 4)

Ī	Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	ZXTP19060CZTA	1M2	7	12	1000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



1M2 = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Collector Voltage (Reverse Blocking)	V _{ECX}	-7	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-4.5	Α
Peak Pulse Current	I _{CM}	-7	Α
Base Current	I _B	-1	Α

Characteristic	Symbol	Value	Unit		
	(Note 5)		1.1 8.8		
	(Note 6)		1.8 14.4	W mW/°C	
Power Dissipation Linear Derating Factor	(Note 7)	P _D	2.4 19.2		
	(Note 8)		4.46 35.7		
	(Note 9)		26.7 213		
	(Note 5)		117		
Thermal Desistance I typetion to Ambient Air	(Note 6)	5	68	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 7)	$R_{ heta JA}$	51		
	(Note 8)		31		
Thermal Resistance, Junction to Lead	(Note 9)	$R_{ heta JL}$	4.7		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

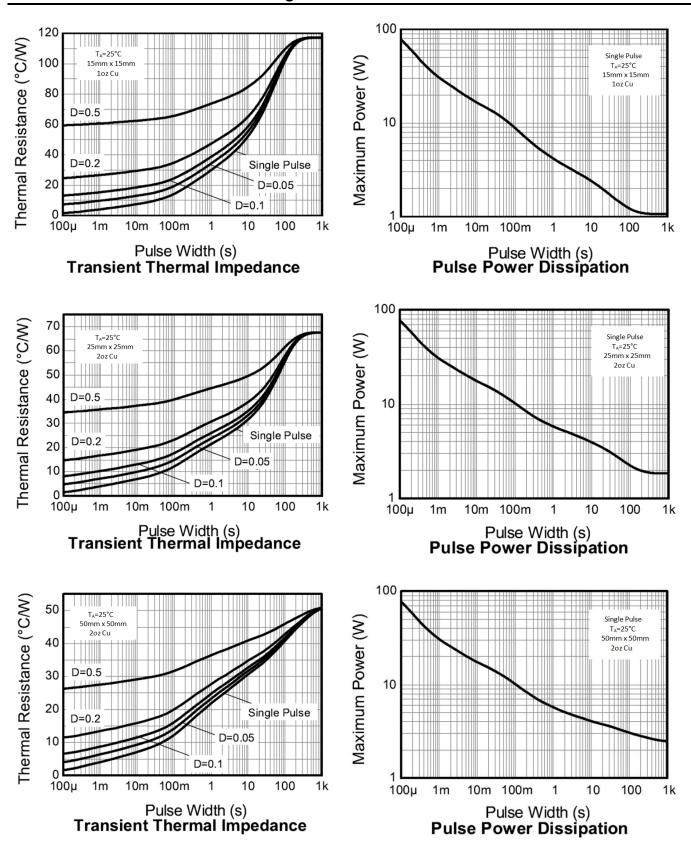
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm × 15mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

 6. Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.
- 8. Same as Note 7, except the device is measured at t<10 seconds.
- Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

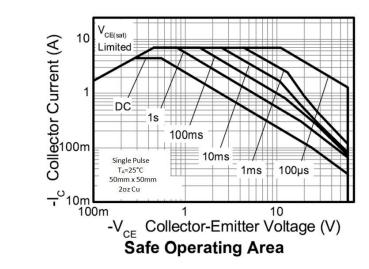


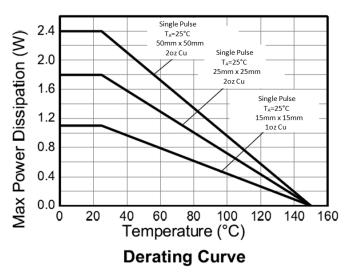
Thermal Characteristics and Derating Information





Thermal Characteristics and Derating Information (cont.)





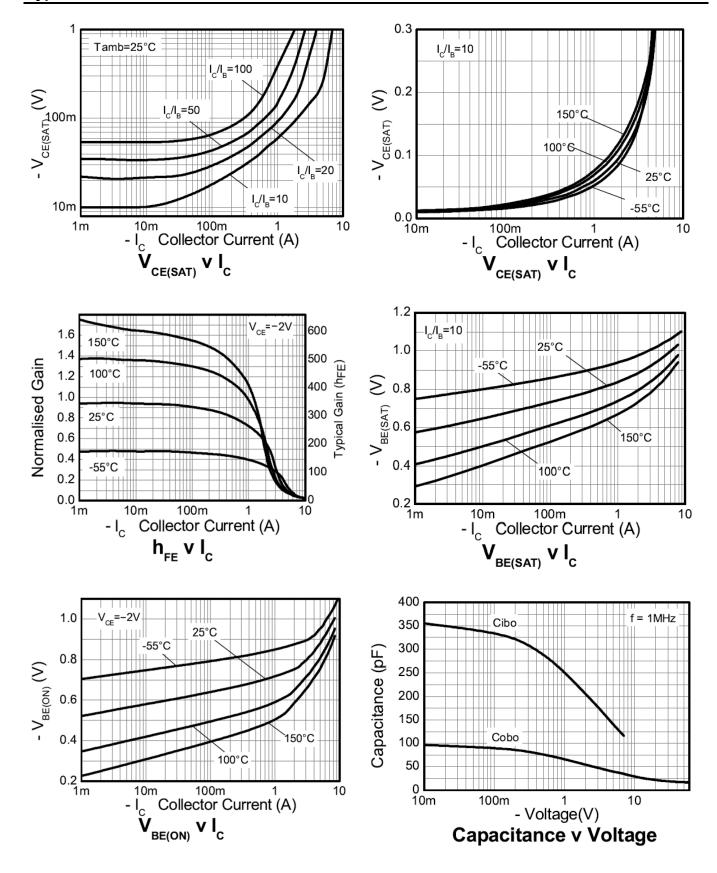
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-60	-110	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-60	-90	_	V	I _C = -10mA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV _{ECX}	-7	-8.4	_	V	I_E = -100μA, R_{BC} <1k Ω or 0.25V > V_{BC} > -0.25V
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV _{ECO}	-7	-8.8	_	V	I _E = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.4	_	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}	-	-1 —	-50 -0.5	nΑ μΑ	V _{CB} = -60V V _{CB} = -60V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_	-1	-50	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 11)	h _{FE}	200 160 25	330 260 45	500 — —	_	I _C = -100mA, V _{CE} = -2V I _C = -1A, V _{CE} = -2V I _C = -4.5A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	_	-62 -150 -500 -105 -145 -240	-80 -205 -750 -165 -200 -410	mV	I_C = -1A, I_B = -100mA I_C = -1A, I_B = -20mA I_C = -2A, I_B = -40mA I_C = -2A, I_B = -200mA I_C = -3A, I_B = -300mA I_C = -4.5A, I_B = -450mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_	-965	-1050	mV	$I_C = -4.5A$, $I_B = -450mA$
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(on)}	_	-875	-1000	mV	I _C = -4.5A, V _{CE} = -2V
Transitional Frequency	f _T	_	180	_	MHz	I_E = -50mA, V_{CE} = -10V f = 50MHz
Input Capacitance	C _{ibo}	_	280	400	pF	V _{EB} = -0.5V, f = 1MHz,
Output Capacitance	C _{obo}	_	29.5	40	pF	V _{CB} = -10V, f = 1MHz,
Delay Time	t _d		24.3	_	ns	
Rise Time	t _r	1	13.2	_	ns	$I_C = -500$ mA, $V_{CC} = -10$ V,
Storage Time	ts		456	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Fall Time	t _f	_	68.2	_	ns	

Note: 11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



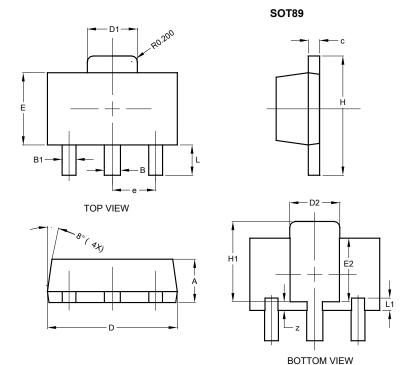
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

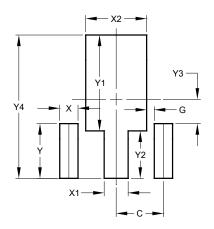


SOT89					
Dim	Min	Max	Тур		
A	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
C	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	1	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	value		
Dilliensions	(in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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